

isc Silicon NPN Power Transistors

MJD50

DESCRIPTION

- DC Current Gain -h_{FE} = 30~150@ I_C= 0.3A
- · Collector-Emitter Sustaining Voltage-
 - : V_{CEO(SUS)} = 400V(Min)
- DPAK for Surface Mount Applications
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

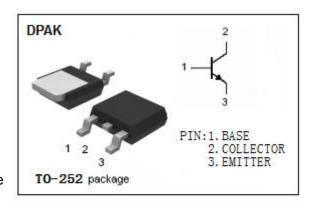
 Designed for line operated audio output amplifier, switchmode power supply drivers and other switching applications

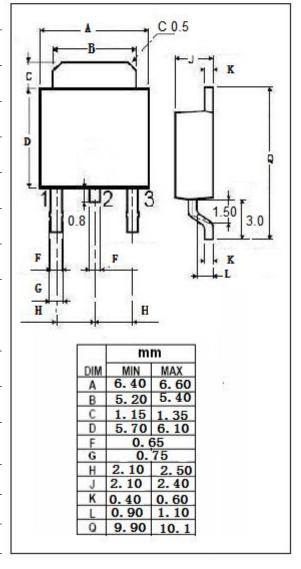
ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	500	V	
V_{CEO}	Collector-Emitter Voltage	400	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current-Continuous	1.0	А	
I _{CM}	Collector Current-Peak	2.0	А	
I _B	Base Current	0.6	А	
P _D	Collector Power Dissipation T_C =25°C	15	W	
	Collector Power Dissipation T _a =25℃	1.56		
T _j	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}$	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	8.33	°C/W
R _{th j-a}	R _{th j-a} Thermal Resistance, Junction to Ambient		°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 30mA; I _B = 0	400		V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 1A; I _B = 0.2A		1.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 1A; V _{CE} = 10V		1.5	V
I _{CEO}	Collector Cutoff Current	V _{CE} = 300V; I _B = 0		0.2	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0		1	mA
Ісво	Collector Cutoff Current	V _{CB} = 500V; I _E = 0		0.1	mA
h _{FE-1}	DC Current Gain	I _C = 0.3A; V _{CE} = 10V	30	150	
h _{FE-2}	DC Current Gain	I _C = 1A; V _{CE} = 10V	10		
f⊤	Current-Gain—Bandwidth Product	I _C = 0.2A; V _{CE} = 10V	10		MHz

Pulse Test: PW≤300µs, Duty Cycle≤2.0%

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